

v03.1007



WIDEBAND LNA MODULE, 2 - 20 GHz

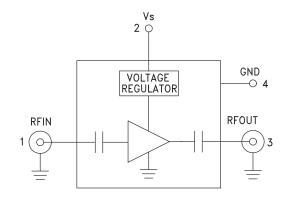


Typical Applications

The HMC-C001 Wideband LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

Functional Diagram



Features

Noise Figure: 2 dB @ 10 GHz

Flat Gain: 15 dB ± 0.5 dB

P1dB Output Power: +14 dBm @ 10 GHz

50 Ohm Matched Input/Output

Regulated Supply + 9V to +15V @ 65mA

Hermetically Sealed Module

Field Replaceable SMA connectors
-55 to +85°C Operating Temperature

General Description

The HMC-C001 is a GaAs MMIC PHEMT Low Noise Distributed Amplifier in a miniature, hermetic module with replaceable SMA connectors which operates between 2 and 20 GHz. The self-biased amplifier provides 15 dB of gain, 2 to 3 dB noise figure and +14 dBm of output power at 1 dB gain compression while requiring a single +12V supply. Gain flatness is excellent from 2 - 18 GHz making the HMC-C001 ideal for EW, ECM RADAR and test equipment applications. The wideband amplifier I/Os are internally matched to 50 Ohms and are internally DC blocked.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vs = +9V to +15V

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	2.0 - 6.0		6.0 - 16.0		16.0 - 20.0		GHz			
Gain	13	15		12	14.5		11	13		dB
Gain Flatness		±.025			±0.5			±0.5		dB
Gain Variation Over Temperature		0.015	0.025		0.015	0.025		0.015	0.025	dB/ °C
Noise Figure		3.5	4.5		2.5	3.5		4.0	5.0	dB
Input Return Loss		15			20			10		dB
Output Return Loss		13			15			8		dB
Output Power for 1 dB Compression (P1dB)	11	14		10	13		8.5	11.5		dBm
Saturated Output Power (Psat)		17			15.5			14		dBm
Output Third Order Intercept (IP3)		25			23			21		dBm
Supply Current		78			78			78		mA

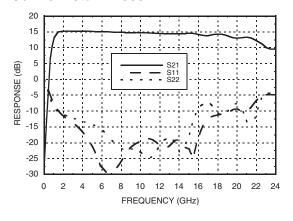


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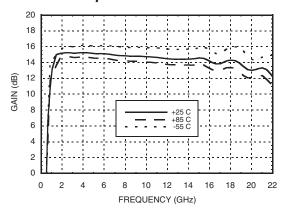


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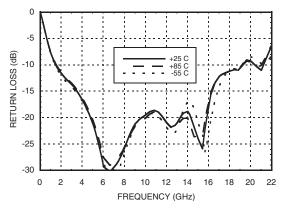
Gain & Return Loss



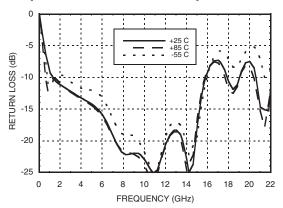
Gain vs. Temperature



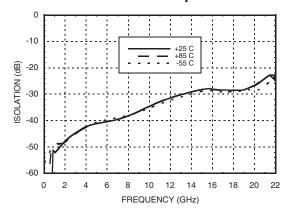
Input Return Loss vs. Temperature



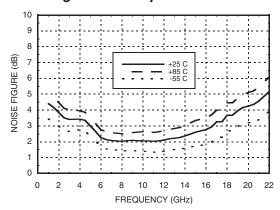
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



Noise Figure vs. Temperature



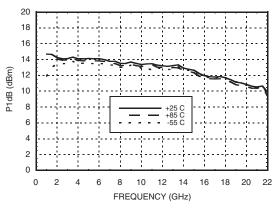


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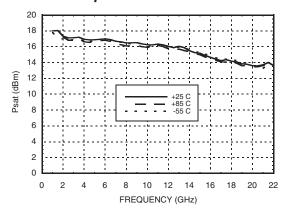


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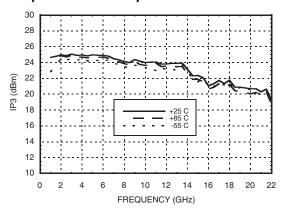
P1dB vs. Temperature



Psat vs. Temperature



Output IP3 vs. Temperature



Absolute Maximum Ratings

Bias Supply Voltage (Vs)	-0.3 Vdc to +25 Vdc
RF Input Power (RFIN)	+23 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



Pin Descriptions

Pin Number	Function	Description	Interface Schematic	
1	RFIN & RF Ground	RF input connector, SMA female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	RFINO— — O———	
2	Vs	Power supply voltage for the amplifier.	VS VOLTAGE REGULATOR	
3	RFOUT & RF Ground	RF output connector, SMA female,field replaceable. This pin is AC coupled and matched to 50 Ohms.	→ → RFOUT	
4	GND	Power supply ground.	○ GND =	

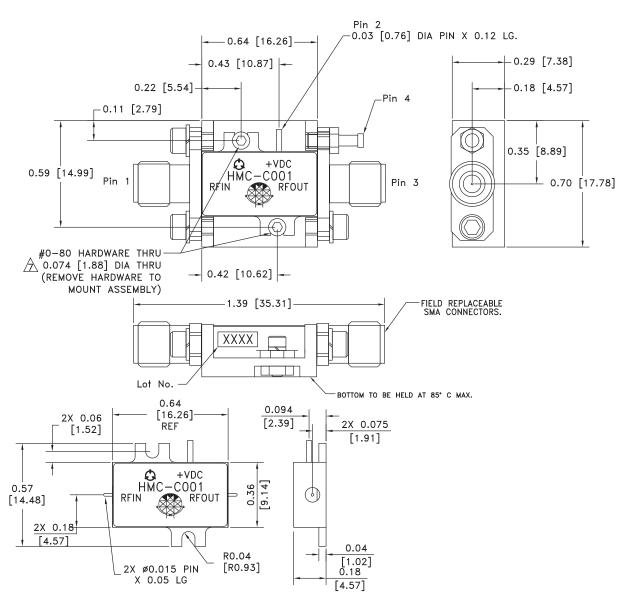
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Outline Drawing



Package Information

· working o minorimum on				
Package Type	C-1			
Package Weight [1]	10.2 gms ^[2]			
Spacer Weight	N/A			

- [1] Includes the connectors
- [2] ±1 gms Tolerance

NOTES:

- 1. PACKAGE. LEADS. COVER MATERIAL: KOVAR™
- 2. BRACKET MATERIAL: ALUMINUM
- 3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
- 4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 5. TOLERANCES ±.005 [0.13] UNLESS OTHERWISE SPECIFIED.
- 6. FIELD REPLACEABLE SMA CONNECTORS. TENSOLITE 5602 5CCSF OR EQUIVALENT.
- ↑TO MOUNT MODULE TO SYSTEM PLATFORM REPLACE 0 -80 HARDWARE WITH DESIRED MOUNTING SCREWS.

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